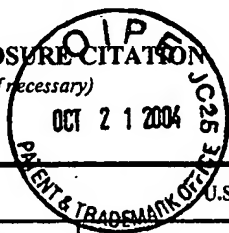


<b>INFORMATION DISCLOSURE CITATION</b> <i>(Use several sheets if necessary)</i>				Docket Number (Optional) <b>OKI.206D3</b>		Application Number <b>10/762,361</b>	
				Applicant(s) <b>Masahiro Yoshida et al.</b>			
				Filing Date <b>January 23, 2004</b>		Group Art Unit <b>2812</b>	

U.S. PATENT DOCUMENTS							
*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE


  

U.S. PATENT APPLICATION PUBLICATIONS							
*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

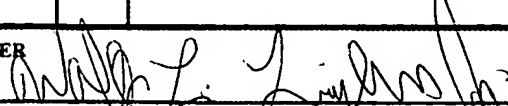
  

FOREIGN PATENT DOCUMENTS								
	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
							YES	NO

OTHER DOCUMENTS		(Including Author, Title, Date, Pertinent Pages, Etc.)
		Focused Technology Report; Report Number: FTR 9912-008; Comparative Analysis of Advanced Sub-Micron Transistor Technology; By Integrated Circuit Engineering Corporation; 1999

EXAMINER 	DATE CONSIDERED <b>1/14/2005</b>
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EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.